TOSHIBA Field Effect Transistor Silicon N Channel MOS Type

SSM3K15FS

High Speed Switching Applications Analog Switching Applications

- Compact package suitable for high-density mounting
- Low ON-resistance $: R_{on} = 4.0 \Omega (max) (@V_{GS} = 4 V)$

 $: R_{on} = 7.0 \Omega (max) (@V_{GS} = 2.5 V)$

Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit	
Drain-Source voltage		V _{DS}	30	V	
Gate-Source voltage		V _{GSS}	±20	V	
Drain current	DC	I _D	100	mA	
	Pulse	I _{DP}	200		
Drain power dissipation (Ta = 25° C)		PD	100	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	



Weight: 2.4 mg (typ.)

Marking





Equivalent Circuit

Handling Precaution

When handling individual devices (which are not yet mounted on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

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Unit: mm

Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GSS}	$V_{GS}=\pm 16~V,~V_{DS}=0$			±1	μA
Drain-Source breakdown voltage		V (BR) DSS	$I_D = 0.1 \text{ mA}, V_{GS} = 0$	30	_	_	V
Drain Cut-off current		I _{DSS}	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0$	_	_	1	μA
Gate threshold voltage		V _{th}	$V_{DS} = 3 \text{ V}, \text{ I}_{D} = 0.1 \text{ mA}$	0.8		1.5	V
Forward transfer admittance		Y _{fs}	$V_{DS} = 3 \text{ V}, \text{ I}_{D} = 10 \text{ mA}$	25			mS
Drain-Source ON resistance		R _{DS (ON)}	$I_{D} = 10 \text{ mA}, V_{GS} = 4 \text{ V}$		2.2	4.0	Ω
			$I_D = 10 \text{ mA}, V_{GS} = 2.5 \text{ V}$		4.0	7.0	
Input capacitance		C _{iss}	$V_{DS} = 3 V, V_{GS} = 0, f = 1 MHz$		7.8		pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 3 V, V_{GS} = 0, f = 1 MHz$		3.6		pF
Output capacitance		C _{oss}	$V_{DS} = 3 V, V_{GS} = 0, f = 1 MHz$	_	8.8		pF
Switching time	Turn-on time	t _{on}	$V_{DD} = 5 \text{ V}, \text{ I}_{D} = 10 \text{ mA}, V_{GS} = 0 \sim 5 \text{ V}$	_	50		ns
	Turn-off time	t _{off}			180		

Switching Time Test Circuit

(a) Test circuit

(b) V_{IN}



Precaution

 V_{th} can be expressed as voltage between gate and source when low operating current value is ID = 100 μA for this product. For normal switching operation, V_{GS} (on) requires higher voltage than V_{th} and V_{GS} (off) requires lower voltage than V_{th} .

(relationship can be established as follows: $V{\rm GS}~({\rm off}) < V{\rm th} < V{\rm GS}~({\rm on})$)

Please take this into consideration for using the device.

 VGS recommended voltage of 2.5 V or higher to turn on this product.

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Handbook" etc.,

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